# NSN 5961-00-919-6816

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**Inclosure Material:** 

Metal

**Overall Length:** 

0.406 inches

### **Overall Diameter:**

0.828 inches

#### **End Application:**

Guided missile, intercept

#### **Mounting Facility Quantity:**

1

### Internal Configuration:

Junction contact

#### Electrode Internally-electrically Connected To Case:

Collector

#### **Mounting Method:**

Threaded stud

# Features Provided:

Hermetically sealed case

#### **Overall Width Across Flats:**

0.865 inches

#### Thread Size:

0.312 inches

#### Criticality Code Justification:

Feat

#### Semiconductor Material:

Silicon

#### Voltage Rating In Volts Per Characteristic:

150.0 breakdown voltage, collector-to-base, emitter open and 90.0 breakdown voltage, collector-to-emitter, base open and 7.0

breakdown voltage, emitter-to-base, collector open

# Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius case

# **Special Features:**

Weapon system essential; junction pattern arrangement: npn

# Thread Series Designator:

Unf

#### **Terminal Type And Quantity:**

3 tab, solder lug

#### **Specification Data:**

80131-release4639 professional/industrial association specification

# Shelf Life:

N/a

# Unit Of Measure:

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Demilitarization:

No

Fiig:

A110a0

